

6MBP150TEA060



Econo IPM series

600V / 150A 6 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

● Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
Bus voltage	DC	V _{DC}	0	450	V	
	Surge	V _{DC(surge)}	0	500	V	
	Short operating	V _{sc}	200	400	V	
Collector-Emitter voltage *1		V _{CES}	0	600	V	
Inverter	Collector current	DC	I _c	-	150	A
		1ms	I _{CP}	-	300	A
		Duty=68.2% *2	-I _c	-	150	A
	Collector power dissipation	One transistor *3	P _c	-	431	W
Supply voltage of Pre-Driver *4		V _{CC}	-0.5	20	V	
Input signal voltage *5		V _{in}	-0.5	V _{CC} +0.5	V	
Input signal current		I _{in}	-	3	mA	
Alarm signal voltage *6		V _{ALM}	-0.5	V _{CC}	V	
Alarm signal current *7		I _{ALM}	-	20	mA	
Junction temperature		T _j	-	150	°C	
Operating case temperature		T _{opr}	-20	100	°C	
Storage temperature		T _{stg}	-40	125	°C	
Solder temperature *8		T _{sol}	-	260	°C	
Isolating voltage (Terminal to base, 50/60Hz sine wave 1min.)		V _{iso}	-	AC2500	V	
Screw torque	Mounting (M5)		-	3.5	N·m	

Note

*1 : V_{ces} shall be applied to the input voltage between terminal P and U or ,u or W, N and U or V or W

*2 : 125°C/FWD R_{th(j-c)}/(I_c x V_F MAX)=125/0.47/(150 x 2.6) x 100=68.2%

*3 : P_c=125°C/IGBT R_{th(j-c)}=125/0.29=431W [Inverter]

*4 : V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 14 and 13

*5 : V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 16,17,18 and 13.

*6 : V_{ALM} shall be applied to the voltage between terminal No.2 and 1, No6 and 5, No10 and 9, No.19 and 13.

*7 : I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

*8 : Immersion time 10±1sec.



6MBP150TEA060

IGBT-IPM

● Electrical characteristics (at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$ unless otherwise specified.)

Main circuit

Item		Symbol	Condition	Min.	Typ.	Max.	Unit	
Inverter	Collector current at off signal input	I_{CES}	$V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_c=150\text{A}$	Terminal	-	-	2.3	V
				Chip	-	1.8	-	
	Forward voltage of FWD	V_F	$-I_c=150\text{A}$	Terminal	-	-	2.6	V
Chip				-	1.6	-		
Turn-on time		t_{on}	$V_{DC}=300\text{V}, T_j=125^\circ\text{C}$	1.2	-	-	μs	
Turn-off time		t_{off}	$I_c=150\text{A}$ Fig.1, Fig.6	-	-	3.6		
Reverse recovery time		t_{rr}	$V_{DC}=300\text{V}, I_c=150\text{A}$ Fig.1, Fig.6	-	-	0.3		
Maximum Avalanche Energy (A non-repetition)		P_{AV}	Internal wiring inductance=50nH Main circuit wiring inductance=54nH	170	-	-	mJ	

● Control circuit

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	I_{ccp}	Switching Frequency : 0 to 15kHz $T_c=-20$ to 125°C Fig.7	-	-	18	mA
Supply current of N-line side pre-driver	I_{ccn}		-	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_Z	$R_{in}=20\text{k ohm}$	-	8.0	-	V
Alarm signal hold time	t_{ALM}	$T_c=-20^\circ\text{C}$ Fig.2	1.1	-	-	ms
		$T_c=25^\circ\text{C}$ Fig.2	-	2.0	-	ms
		$T_c=125^\circ\text{C}$ Fig.2	-	-	4.0	ms
Current limit resistor	R_{ALM}	Alarm terminal	1425	1500	1575	ohm

● Protection Section ($V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	I_{oc}	$T_j=125^\circ\text{C}$	225	-	-	A
Over Current Protection Delay time	t_{DOC}	$T_j=125^\circ\text{C}$	-	5	-	μs
SC Protection Delay time	t_{SC}	$T_j=125^\circ\text{C}$ Fig.4	-	-	8	μs
IGBT Chip Over Heating	T_{jOH}	Surface of IGBT chips	150	-	-	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{jH}		-	20	-	$^\circ\text{C}$
Under Voltage Protection Level	V_{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V_H		0.2	0.5	-	V

● Thermal characteristics($T_c=25^\circ\text{C}$)

Item	Symbol		Min.	Typ.	Max.	Unit	
Junction to Case thermal resistance *10	Inverter	IGBT	$R_{th(j-c)}$	-	-	0.29	$^\circ\text{C/W}$
		FWD	$R_{th(j-c)}$	-	-	0.47	$^\circ\text{C/W}$
Case to fin thermal resistance with compound	$R_{th(c-f)}$		-	0.05	-	$^\circ\text{C/W}$	

*10 : (For 1 device, Case is under the device)

● Noise Immunity ($V_{DC}=300\text{V}$, $V_{cc}=15\text{V}$, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width $1\mu\text{s}$, polarity \pm , 10minuets Judge : no over-current, no miss operating	± 2.0	-	-	kV
Common mode lightning surge	Rise time $1.2\mu\text{s}$, Fall time $50\mu\text{s}$ Interval 20s, 10 times Judge : no over-current, no miss operating	± 5.0	-	-	kV

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	V_{DC}	-	-	400	V
Operating Supply Voltage of Pre-Driver	V_{cc}	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

● Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	W_t	-	270	-	g

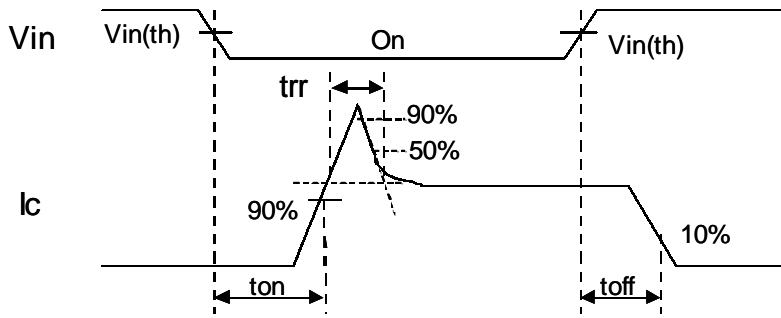
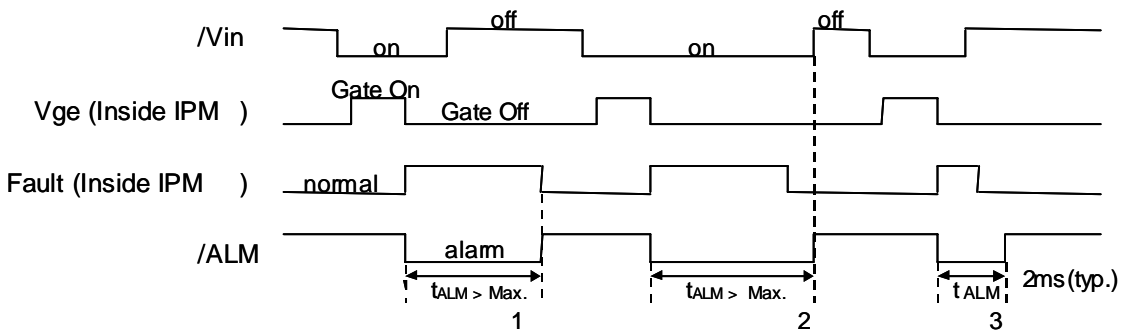


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input/Output Timing Diagram

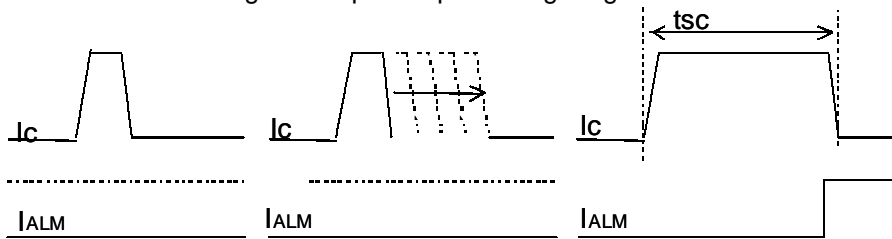


Figure.4 Definition of tsc

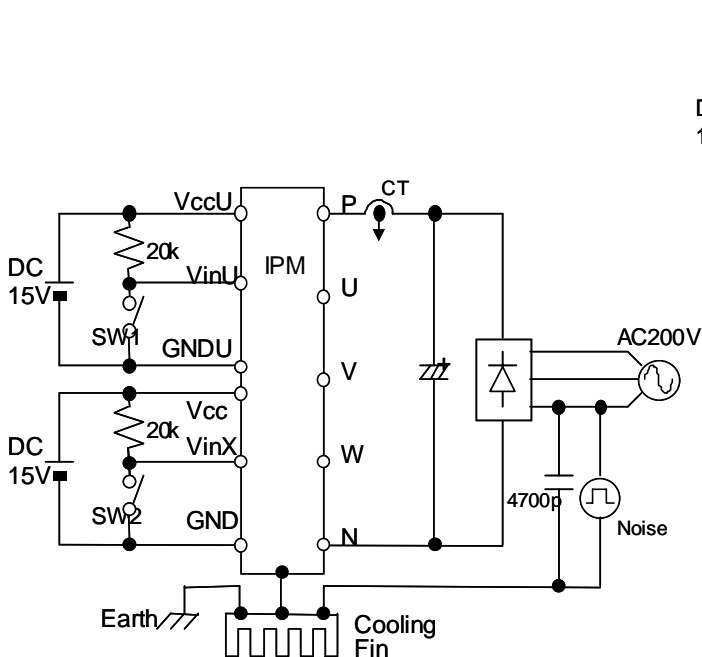


Figure 5. Noise Test Circuit

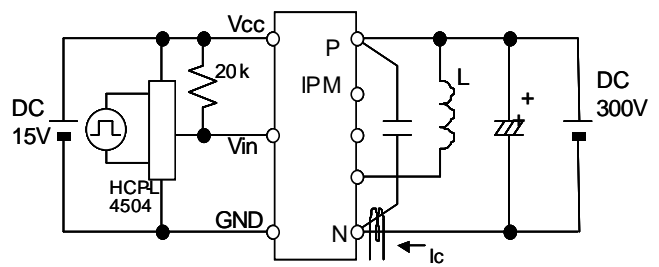


Figure 6. Switching Characteristics Test Circuit

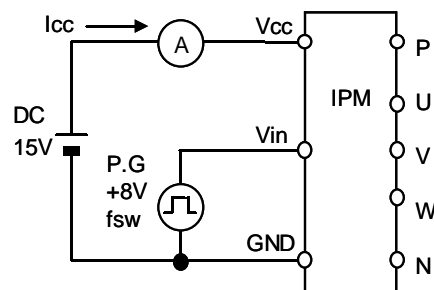
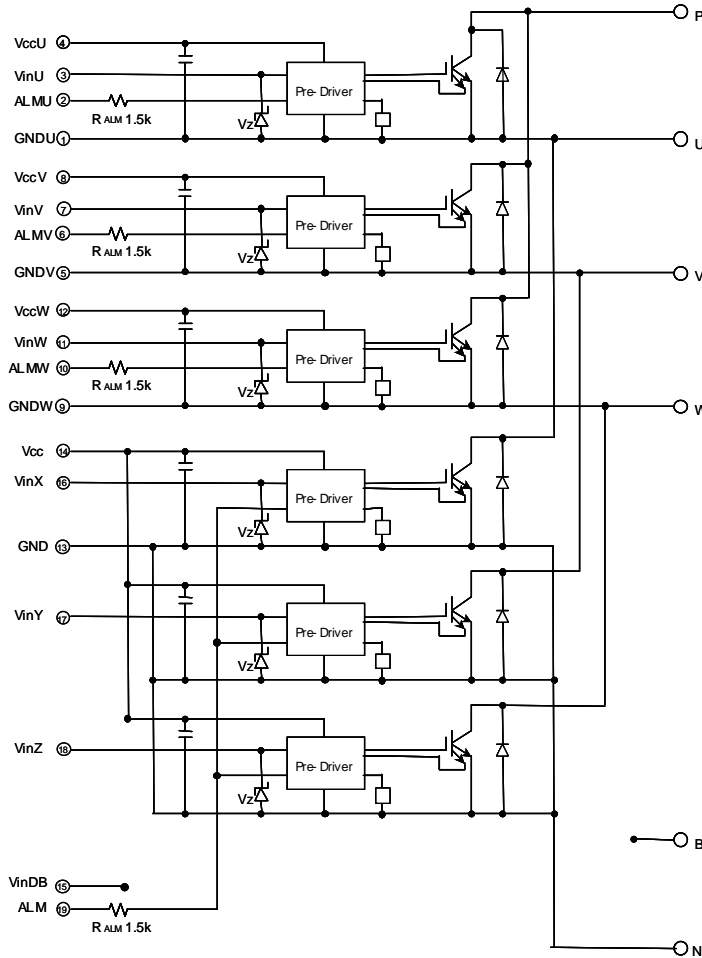


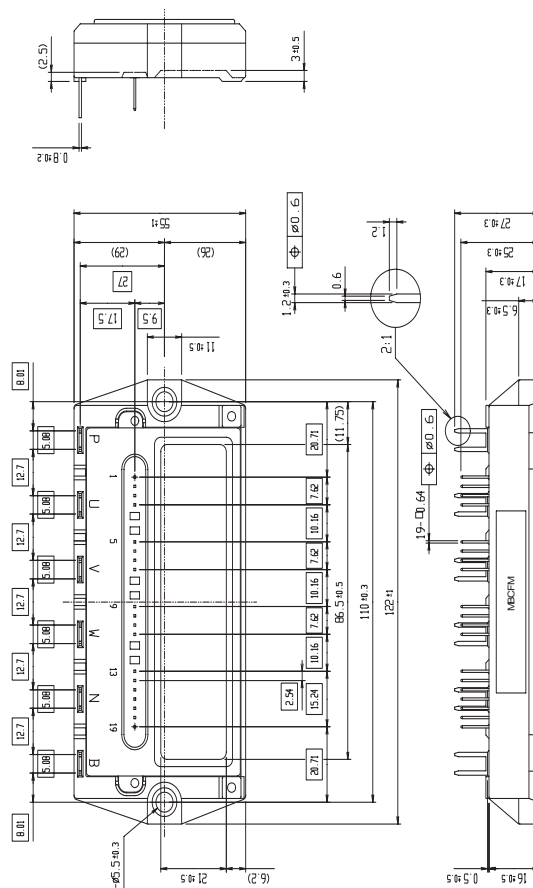
Figure 7. Icc Test Circuit

Block diagram



- Pre-drivers include following functions
1. Amplifier for driver
 2. Short circuit protection
 3. Under voltage lockout circuit
 4. Over current protection
 5. IGBT chip over heating protection

Outline drawings, mm

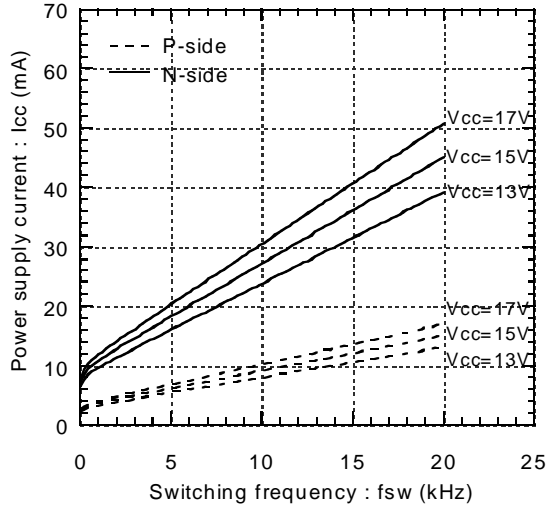


Mass : 270g

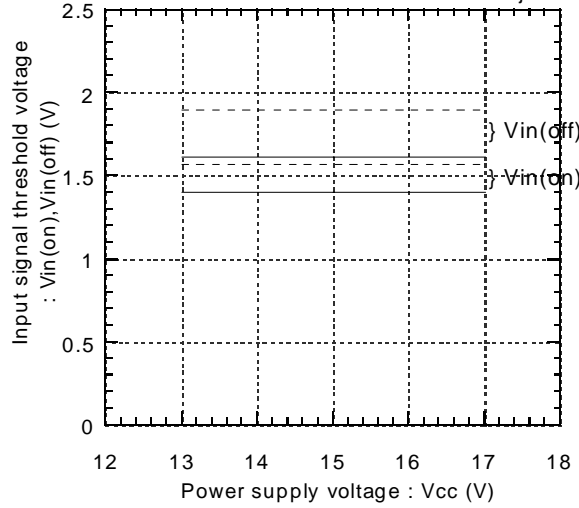
Characteristics

Control circuit characteristics (Representative)

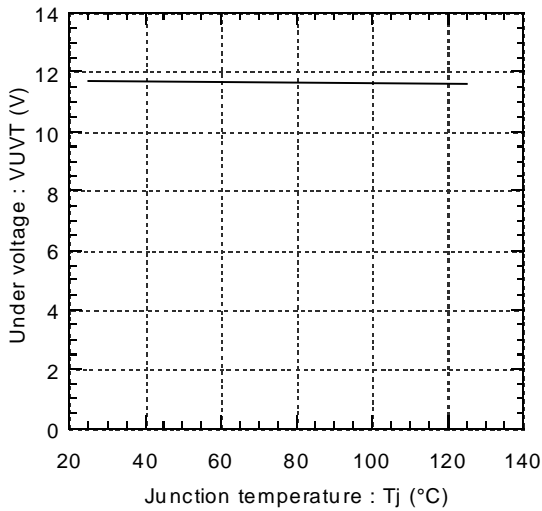
Power supply current vs. Switching frequency
Tc=125°C



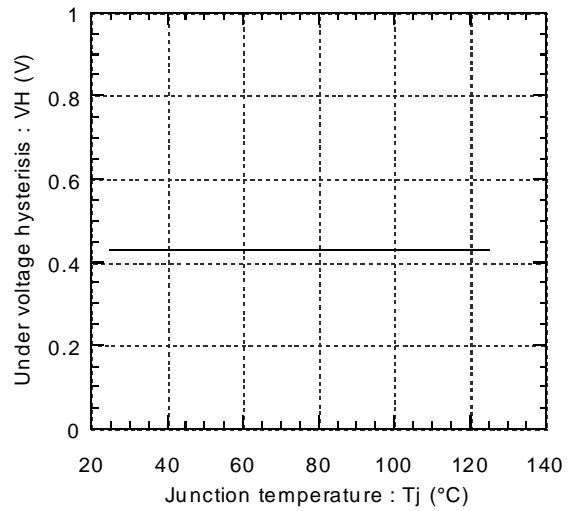
Input signal threshold voltage vs. Power supply voltage
— Tj=25°C
--- Tj=125°C



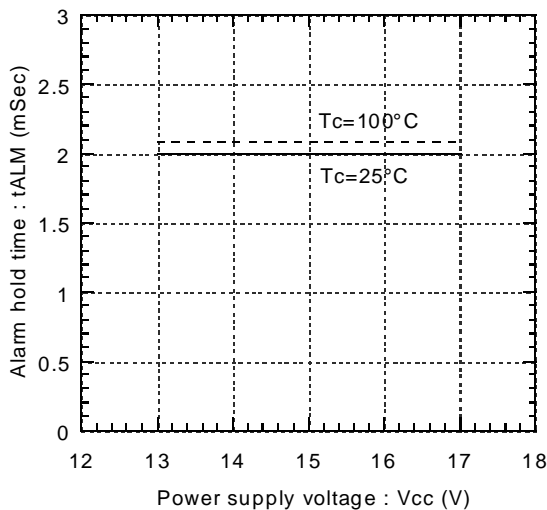
Under voltage vs. Junction temperature



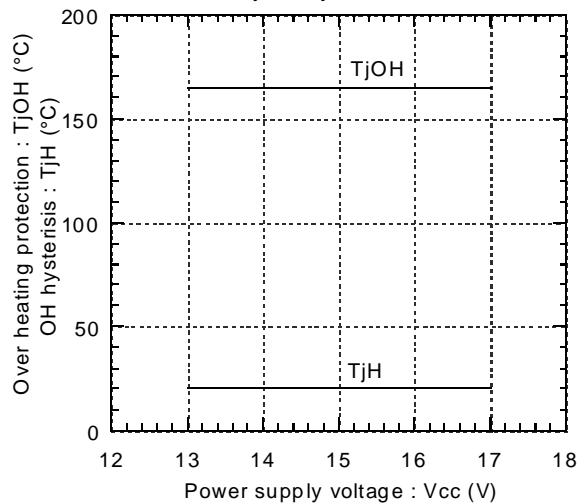
Under voltage hysteresis vs. Junction temperature



Alarm hold time vs. Power supply voltage

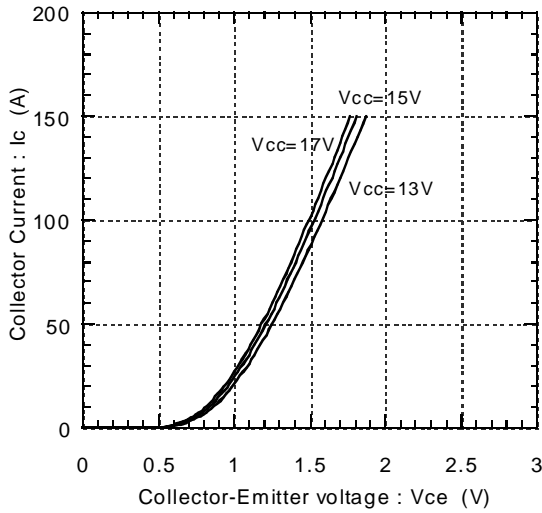


Over heating characteristics
TjOH, TjH vs. Vcc

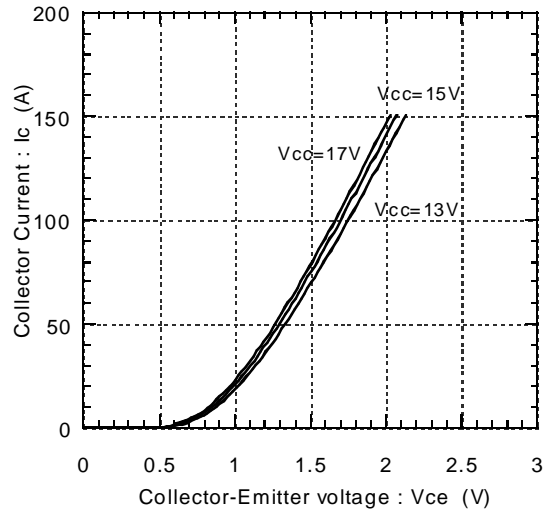


● Main circuit characteristics (Representative)

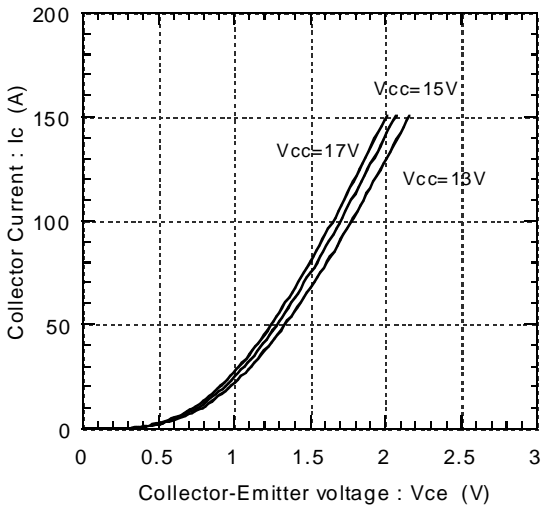
Collector current vs. Collector-Emmitter voltage
Tj=25°C(Chip)



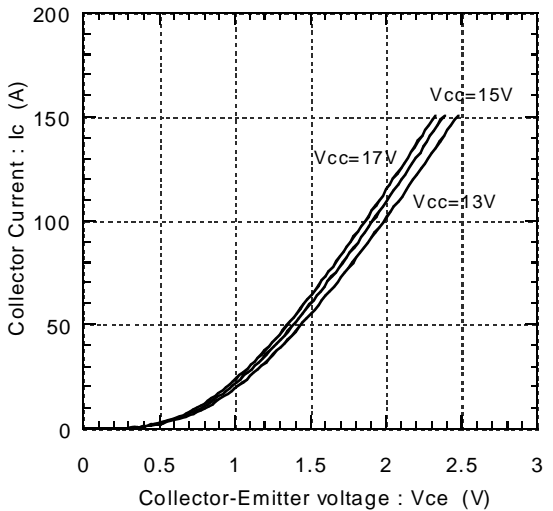
Collector current vs. Collector-Emmitter voltage
Tj=25°C(Terminal)



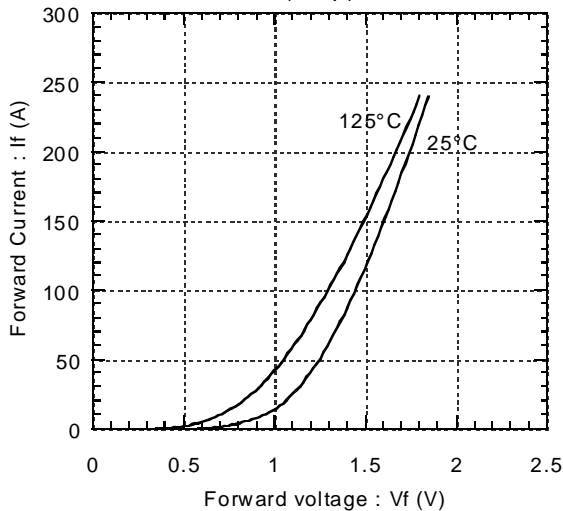
Collector current vs. Collector-Emmitter voltage
Tj=125°C(Chip)



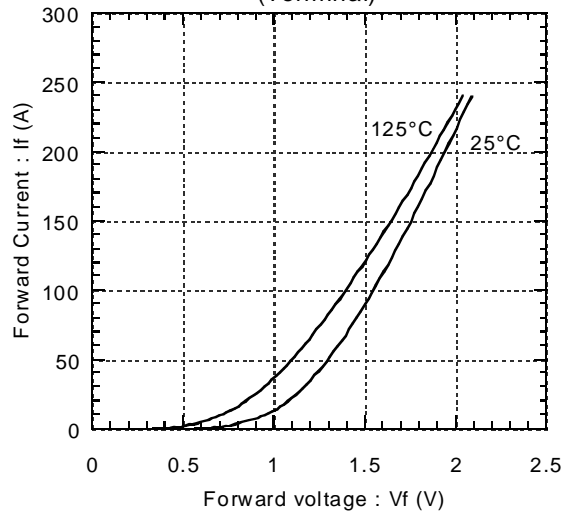
Collector current vs. Collector-Emmitter voltage
Tj=125°C(Terminal)

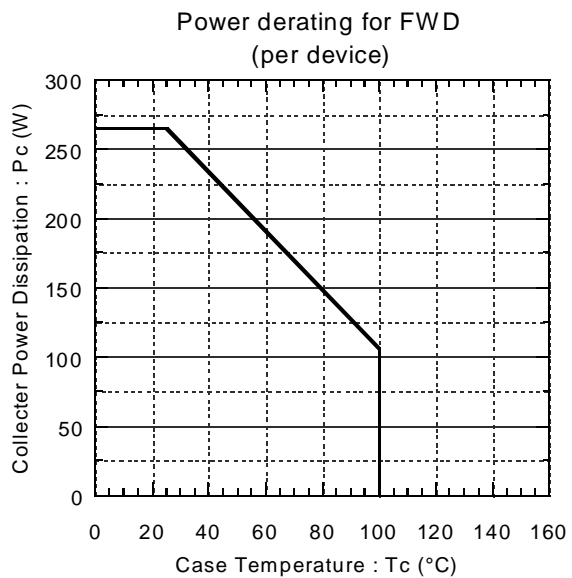
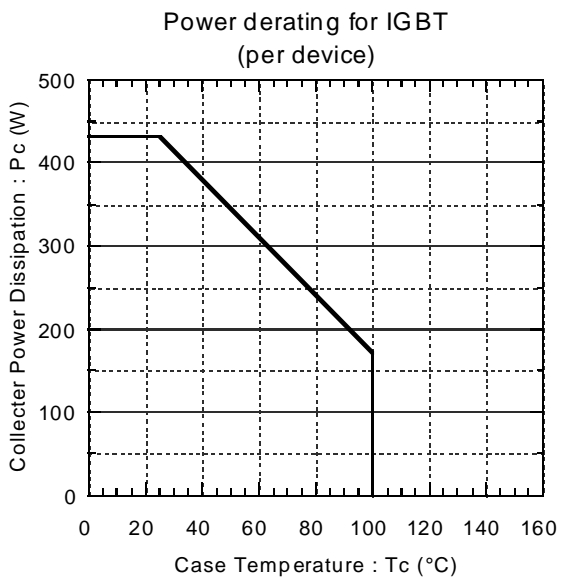
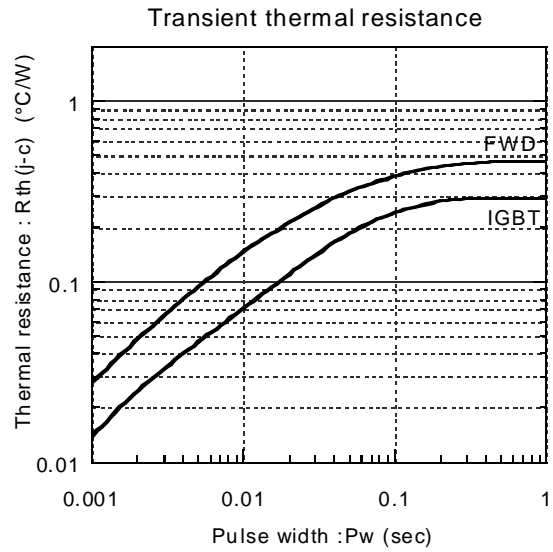
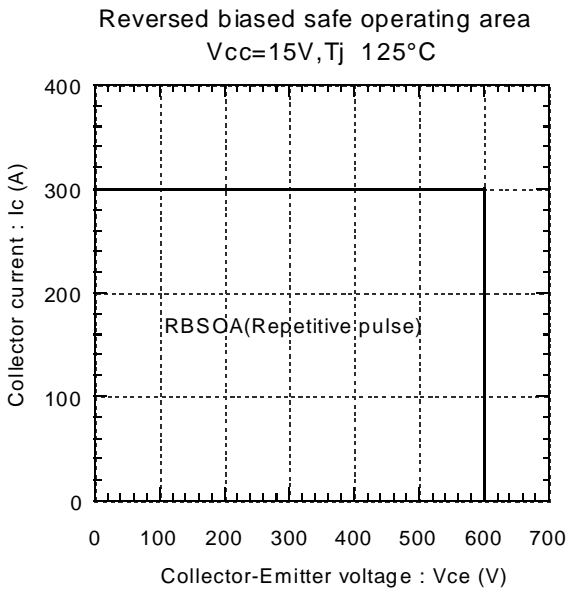
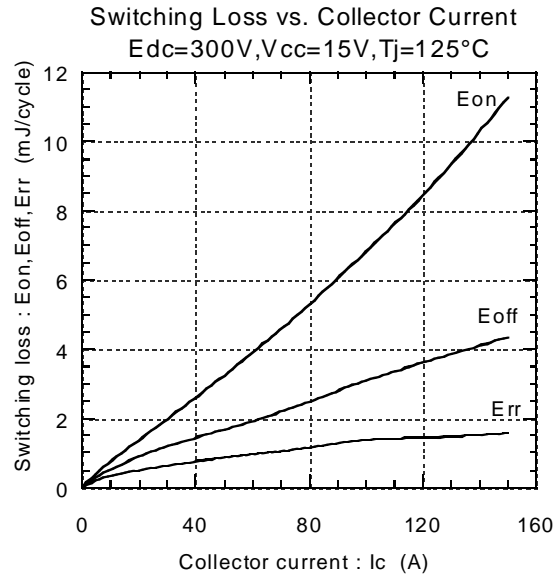
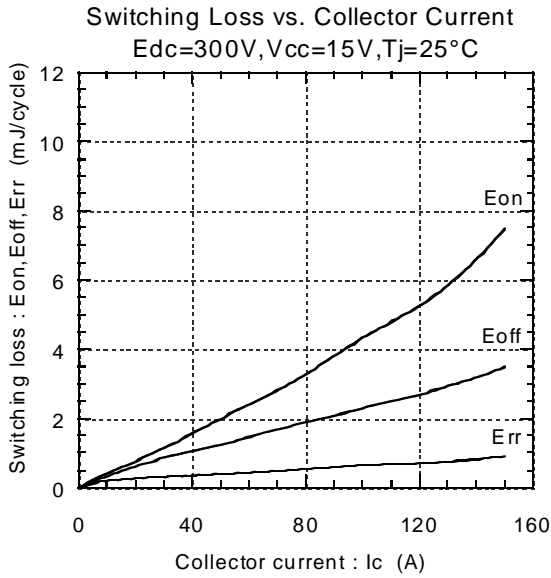


Forward current vs. Forward voltage
(Chip)

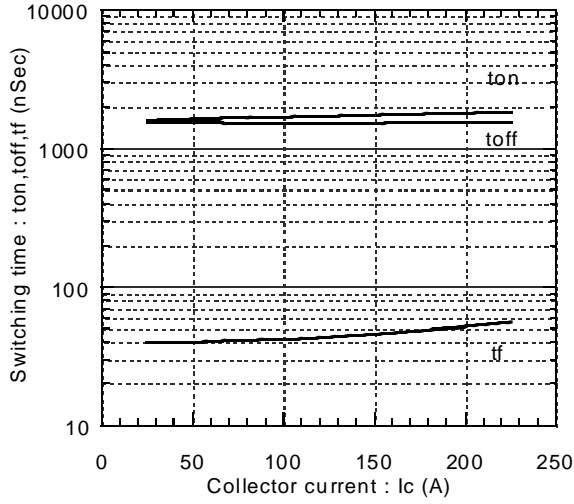


Forward current vs. Forward voltage
(Terminal)

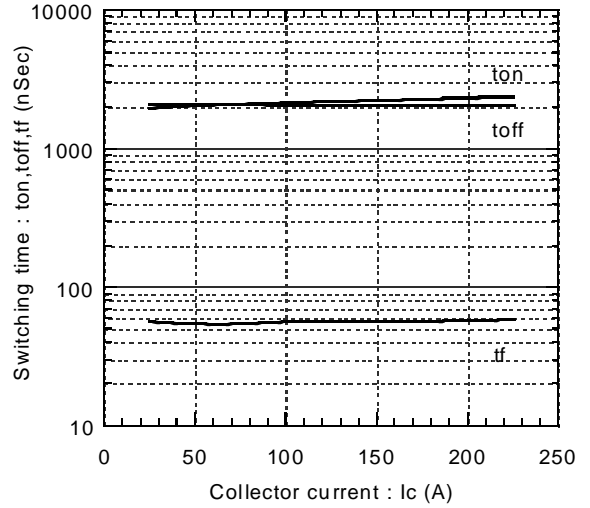




Switching time vs. Collector current
 $E_{dc}=300V, V_{cc}=15V, T_j=25^\circ C$



Switching time vs. Collector current
 $E_{dc}=300V, V_{cc}=15V, T_j=125^\circ C$



Reverse recovery characteristics
 t_{rr}, I_{rr} vs. I_F

